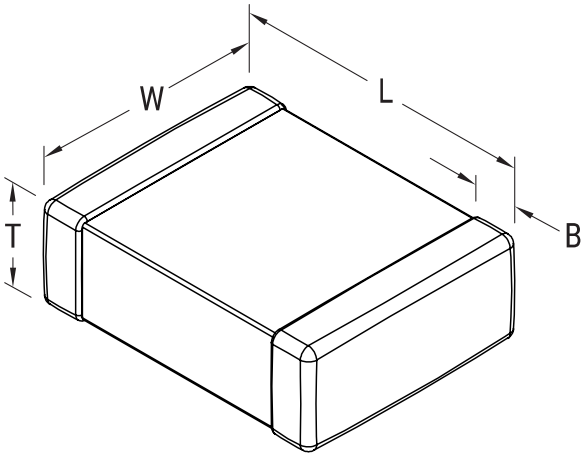
CBR08C859D1GAC

CBR-SMD RF C0G, Ceramic, 8.5 pF, +/-0.5 pF, 100 VDC, C0G, SMD, Fixed, RF, Ultra High Q, Low ESR, Class I, 0805 / 2012



Click here for the 3D model.

General Information	
Series	CBR-SMD RF C0G
Style	SMD Chip
Description	SMD, Fixed, RF, Ultra High Q, Low ESR, Class I
Features	Ultra High Q, Low ESR, Class I
RoHS	Yes
Termination	Tin
Marking	No
Typical Component Weight	12.03 mg
Notes	Solder Wave or Solder Reflow.
Shelf Life	78 Weeks
MSL	1

Dimensions	
L	2mm +/-0.2mm
W	1.25mm +/-0.2mm
T	0.85mm +/-0.1mm
B	0.5mm +/-0.2mm
Case Code (EIA / mm)	0805 / 2012

Packaging Specifications	
Packaging	T&R, 180mm, Plastic Tape
Packaging Quantity	4000

Specifications	
Capacitance	8.5 pF
Tolerance	+/-0.5 pF
Voltage DC	100 VDC
Dielectric Withstanding Voltage	250 VDC
Temperature Range	-55/+125°C
Temp. Coefficient	C0G
Dissipation Factor	0.175%
Aging Rate	0% Loss/Decade Hour
Insulation Resistance	10 GOhms
Quality Factor	570

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